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Reference Design



INA203, INA204, INA205

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INA20x Unidirectional Measurement Current-Shunt Monitor With Dual Comparators

1 Features

- **Complete Current Sense Solution**
- Three Gain Options Available:
 - INA203 = 20 V/V
 - INA204 = 50 V/V
 - INA205 = 100 V/V
- **Dual Comparators:**
 - Comparator 1 With Latch
 - Comparator 2 With Optional Delay
- Common-Mode Range: -16 V to 80 V
- High Accuracy: 3.5% (Maximum) Over Temperature
- Bandwidth: 500 kHz
- Quiescent Current: 1.8 mA
- Packages: SO-14, TSSOP-14, VSSOP-10

2 Applications

- **Notebook Computers**
- Cell Phones
- **Telecom Equipment**
- Automotive
- Power Management
- **Battery Chargers**
- Welding Equipment

3 Description

The INA203, INA204, and INA205 are a family of unidirectional current-shunt monitors with voltage output, dual comparators, and voltage reference. The INA203, INA204, and INA205 can sense drops across shunts at common-mode voltages from -16 V to 80 V. The INA203, INA204, and INA205 are available with three output voltage scales: 20 V/V. 50 V/V, and 100 V/V, with up to 500-kHz bandwidth.

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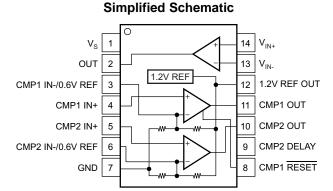
The INA203, INA204, and INA205 also incorporate two open-drain comparators with internal 0.6-V references. On 14-pin versions, the comparator references can be overridden by external inputs. Comparator 1 includes a latching capability, and Comparator 2 has a user-programmable delay. 14-pin versions also provide a 1.2-V reference output.

The INA203, INA204, and INA205 operate from a single 2.7-V to 18-V supply. They are specified over the extended operating temperature range of -40°C to 125°C.

Device Information ⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
INA203, INA204, INA205	SOIC (14)	8.65 mm × 3.91 mm
	VSSOP (10)	3.00 mm × 3.00 mm
	TSSOP (14)	5.00 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.





INA203, INA204, INA205

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

C	hanges from Revision D (May 2009) to Revision E	Page
•	Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section	
•	Moved thermal values from <i>Electrical Characteristics: General</i> to <i>Thermal Information</i> table. Removed duplicate storage temperature parameter.	9
C	hanges from Revision C (October 2007) to Revision D	Page
•	Changed Figure 1	8

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INA203, INA204, INA205

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5 Device Comparison

Table 1. Device Gain

DEVICE	GAIN
INA203	20 V/V
INA204	50 V/V
INA205	100 V/V

Table 2. Related Products

FEATURES	PRODUCT
Variant of INA203–INA205 Comparator 2 polarity	INA206–INA208
Current-shunt monitor with single Comparator and V _{REF}	INA200-INA202
Current-shunt monitor only	INA193–INA198
Current-shunt monitor with split stages for filter options	INA270–INA271

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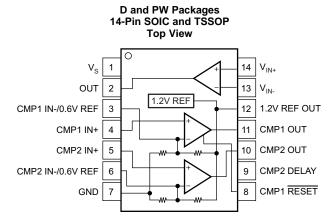
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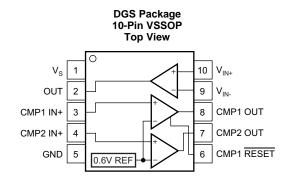
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6 Pin Configuration and Functions





Pin Functions

	PIN			
NAME	SOIC, TSSOP	VSSOP	I/O	DESCRIPTION
Vs	1	1	I	Power Supply
OUT	2	2	0	Output voltage
CMP1 IN-/0.6 V Ref	3	_	I	Comparator 1 negative input, can be used to override the internal 0.6-V reference
CMP1 IN+	4	3	I	Comparator 1 positive input
CMP2 IN+	5	—	I	Comparator 2 positive input
CMP2 IN-	_	4	I	Comparator 2 negative input
CMP2 IN-/0.6- V Ref	6	_	I	Comparator 2 negative input, can be used to override the internal 0.6-V reference
GND	7	5	I	Ground
CMP1 RESET	8	6	I	Comparator 1 ouput reset, active low
CMP2 DELAY	9	—	I	Connect an optional capacitor to adjust comparator 2 delay
CMP2 OUT	10	7	0	Comparator 2 output
CMP1 OUT	11	8	0	Comparator 1 output
1.2-V REF OUT	12	_	0	1.2-V reference output
VIN-	13	9	I	Connect to shunt low side
VIN+	14	10	I	Connect to shunt high side



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7 Specifications

7.1 Absolute Maximum Ratings

See $^{(1)}$

		MIN	MAX	UNIT
Supply Voltage, V _s			18	V
Current-Shunt Monitor Analog	Differential $(V_{IN+}) - (V_{IN-})$	-18	18	V
Inputs, V_{IN+} and V_{IN-}	Common-Mode	-16	80	V
Comparator Analog Input and Re	eset Pins	GND – 0.3	(Vs) + 0.3	V
Analog Output, Out Pin		GND – 0.3	(Vs) + 0.3	V
Comparator Output, Out Pin		GND – 0.3	18	V
V _{REF} and CMP2 Delay Pin		GND – 0.3	10	V
Input Current Into Any Pin			5	mA
Operating Temperature		-55	150	°C
Junction Temperature		-65	150	°C
Storage temperature, T _{stg}		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±4000	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins $^{\rm (2)}$	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	NOM	MAX	UNIT
Vcm Common-mode input voltage	-16	12	80	V
Vs Operating supply voltage	2.7	12	18	V
T _A Operating free-air temperature	-40	25	125	°C

7.4 Thermal Information

			INA20x			
	THERMAL METRIC ⁽¹⁾	D (SOIC)	DGS (VSSOP)	PW (TSSOP)	UNIT	
		14 PINS	10 PINS	14 PINS		
R_{\thetaJA}	Junction-to-ambient thermal resistance	84.9	161.3	112.6	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	44	36.8	37.2	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	39.4	82.3	55.4	°C/W	
ΨJT	Junction-to-top characterization parameter	10.3	1.3	2.7	°C/W	
Ψ _{JB}	Junction-to-board characterization parameter	39.1	80.8	54.7	°C/W	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	150	200	150	°C/W	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

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7.5 Electrical Characteristics: Current-Shunt Monitor

At $T_A = 25^{\circ}$ C, $V_S = 12$ V, $V_{CM} = 12$ V, $V_{SENSE} = 100$ mV, $R_L = 10$ k Ω to GND, $R_{pullup} = 5.1$ k Ω each connected from CMP1 OUT and CMP2 OUT to V_S , and CMP1 IN+ = 1 V and CMP2 IN- = GND, unless otherwise noted.

PARAMETER	TEST CON	NDITIONS	MIN	ТҮР	MAX	UNIT
INPUT						
Full-Scale Sense Input Voltage	$V_{\text{SENSE}} = V_{\text{IN+}} - V_{\text{IN-}}$			0.15	(V _S – 0.25)/Gain	V
Common-Mode Input V _{CM}		T _A = -40°C to 125°C	-16		80	V
Common-Mode Rejection CMRR Ratio	$V_{CM} = -16$ V to 80 V		80	100		dB
Over Temperature	V_{CM} = 12 V to 80 V	T _A = -40°C to 125°C	100	123		dB
Offset Voltage, RTI ⁽¹⁾ V _{OS}		I		±0.5	±2.5	mV
25°C to 125°C					±3	mV
-40°C to 25°C					±3.5	mV
vs Temperature dV _{OS} /dT	T_{MIN} to T_{MAX}	T _A = −40°C to 125°C		5		µV/°C
vs Power Supply PSR	V _{OUT} = 2 V, V _{CM} = 18 V, 2.7 V	T _A = -40°C to 125°C		2.5	100	μV/V
Input Bias Current, I _B		T _A = −40°C to 125°C		±9	±16	μA
OUTPUT (V _{SENSE} ≥ 20 mV)						
Gain: G						
INA203				20		V/V
INA204				50		V/V
INA205				100		V/V
Gain Error	$V_{SENSE} = 20 \text{ mV}$ to 100	0 mV		±0.2%	±1%	
Over Temperature	V _{SENSE} = 20 mV to 100 mV	T _A = −40°C to 125°C			±2%	
Total Output Error ⁽²⁾	V_{SENSE} = 120 mV, V_{S} = 16 V			±0.75%	±2.2%	
Over Temperature	V_{SENSE} = 120 mV, V_{S} = 16 V	$T_A = -40^{\circ}C$ to 125°C			±3.5%	
Nonlinearity Error ⁽³⁾	V _{SENSE} = 20 mV to 10	0 mV		±0.002%		
Output Impedance, Pin 2 R _O				1.5		Ω
Maximum Capacitive Load	No Sustained Oscillation	on		10		nF
OUTPUT (V_{SENSE} < 20 mV) ⁽⁴⁾						
INA203, INA204, INA205	$-16 \text{ V} \le \text{V}_{\text{CM}} < 0 \text{ V}$			300		mV
INA203	$0 V \le V_{CM} \le V_S, V_S = \xi$	5 V			0.4	V
INA204	$0 V \le V_{CM} \le V_S, V_S = \xi$	5 V			1	V
INA205	$0 \text{ V} \leq \text{V}_{\text{CM}} \leq \text{V}_{\text{S}}, \text{ V}_{\text{S}} = 5 \text{ V}$				2	V
INA203, INA204, INA205	$V_{\rm S} < V_{\rm CM} \le 80 \ V$			300		mV
VOLTAGE OUTPUT ⁽⁵⁾						
Output Swing to the Positive Rail	V _{IN-} = 11 V, V _{IN+} = 12 V	$T_A = -40^{\circ}C$ to 125°C		(Vs) – 0.15	(Vs) – 0.25	V
Output Swing to GND ⁽⁶⁾	V _{IN-} = 0 V, V _{IN+} = -0.5 V	T _A = -40°C to 125°C	(V ₀	_{GND}) + 0.004	(V _{GND}) + 0.05	V

(1) Offset is extrapolated from measurements of the output at 20 mV and 100 mV V_{SENSE} .

(2) Total output error includes effects of gain error and V_{OS}.

(3) Linearity is best fit to a straight line.

(4) For details on this region of operation, see the Accuracy Variations as a Result Of V_{SENSE} and Common-Mode Voltage section in the Application and Implementation.

(5) See Typical Characteristic curve Positive Output Voltage Swing vs Output Current (Figure 8).

(6) Specified by design; not production tested.

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Electrical Characteristics: Current-Shunt Monitor (continued)

At $T_A = 25^{\circ}$ C, $V_S = 12$ V, $V_{CM} = 12$ V, $V_{SENSE} = 100$ mV, $R_L = 10$ k Ω to GND, $R_{pullup} = 5.1$ k Ω each connected from CMP1 OUT and CMP2 OUT to V_S , and CMP1 IN+ = 1 V and CMP2 IN- = GND, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	ТҮР	MAX	UNIT				
FREQUENCY RESPONSE	FREQUENCY RESPONSE									
Bandwidth:	BW									
INA203		C _{LOAD} = 5 pF		500		kHz				
INA204		C _{LOAD} = 5 pF		300		kHz				
INA205		C _{LOAD} = 5 pF		200		kHz				
Phase Margin		C _{LOAD} < 10 nF		40						
Slew Rate	SR			1		V/µs				
Settling Time (1%)		V_{SENSE} = 10 mV _{PP} to 100 mV _{PP} , C _{LOAD} = 5 pF		2		μs				
NOISE, RTI										
Output Voltage Noise Dens	sity			40		nV/√Hz				

7.6 Electrical Characteristics: Comparator

At $T_A = 25^{\circ}$ C, $V_S = 12$ V, $V_{CM} = 12$ V, $V_{SENSE} = 100$ mV, $R_L = 10$ k Ω to GND, and $R_{pullup} = 5.1$ k Ω each connected from CMP1 OUT and CMP2 OUT to V_S , unless otherwise noted.

PARAMETER	TEST CON	NDITIONS	MIN	ТҮР	MAX	UNIT
OFFSET VOLTAGE	÷					
Offset Voltage	Comparator Common-Mc Voltage	ode Voltage = Threshold		2		mV
Offset Voltage Drift, Comparator 1		$T_A = -40^{\circ}C$ to $125^{\circ}C$		±2		µV/°C
Offset Voltage Drift, Comparator 2		$T_A = -40^{\circ}C$ to $125^{\circ}C$		5.4		µV/°C
Threshold	$T_A = 25^{\circ}C$		590	608	620	mV
Over Temperature		$T_A = -40^{\circ}C$ to $125^{\circ}C$	586		625	mV
Hysteresis ⁽¹⁾ , CMP1	$T_A = -40^{\circ}C$ to $85^{\circ}C$			-8		mV
Hysteresis ⁽¹⁾ , CMP2	$T_A = -40^{\circ}C$ to $85^{\circ}C$			8		mV
INPUT BIAS CURRENT ⁽²⁾						
CMP1 IN+, CMP2 IN+				0.005	10	nA
vs Temperature		$T_A = -40^{\circ}C$ to $125^{\circ}C$			15	nA
INPUT IMPEDANCE						
Pins 3 and 6 (14-pin packages only)				10		kΩ
INPUT RANGE						
CMP1 IN+ and CMP2 IN+				0 V to V _S – 1.5 V		V
Pins 3 and 6 (14-pin packages only) ⁽³⁾				0 V to V_{S} – 1.5 V		V
OUTPUT						
Large-Signal Differential Voltage Gain	CMP V _{OUT} 1 V to 4 V, R _L 5 V	≥ 15 k Ω Connected to		200		V/mV
High-Level Output Current	$V_{ID} = 0.4 \text{ V}, V_{OH} = V_S$			0.0001	1	μA
Low-Level Output Voltage	V _{ID} = -0.6 V, I _{OL} = 2.35 n	$V_{ID} = -0.6 \text{ V}, I_{OL} = 2.35 \text{ mA}$			300	mV
RESPONSE TIME ⁽⁴⁾						

(1) Hysteresis refers to the threshold (the threshold specification applies to a rising edge of a noninverting input) of a falling edge on the noninverting input of the comparator; refer to Figure 1.

(2) Specified by design; not production tested.

(3) See the Comparator Maximum Input Voltage Range section in the Application and Implementation.

(4) The comparator response time specified is the interval between the input step function and the instant when the output crosses 1.4 V.

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Electrical Characteristics: Comparator (continued)

At $T_A = 25^{\circ}$ C, $V_S = 12$ V, $V_{CM} = 12$ V, $V_{SENSE} = 100$ mV, $R_L = 10$ k Ω to GND, and $R_{pullup} = 5.1$ k Ω each connected from CMP1 OUT and CMP2 OUT to V_S , unless otherwise noted.

PARAMETE	R	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT
Comparator 1		R_L to 5 V, C_L = 15 pF, 100-mV Input Step with 5-mV Overdrive 1.				μs
Comparator 2		R_L to 5 V, C_L = 15 pF, 100-mV Input Step with 5-mV Overdrive, C_{DELAY} Pin Open		1.3		μs
RESET		·				
RESET Threshold (5)				1.1		V
Logic Input Impedance				2		MΩ
Minimum RESET Pulse	e Width			1.5		μs
RESET Propagation De	elay			3		μs
Comparator 2 Delay Ec	quation ⁽⁶⁾		C _{DELAY} =	t _D /5		μF
Comparator 2 Delay	t _D	$C_{\text{DELAY}} = 0.1 \mu\text{F}$		0.5		S

(5) The CMP1 RESET input has an internal 2-MΩ (typical) pulldown. Leaving the CMP1 RESET open results in a LOW state, with transparent comparator operation.

(6) The Comparator 2 delay applies to both rising and falling edges of the comparator output.







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7.7 Electrical Characteristics: Reference

At $T_A = 25^{\circ}$ C, $V_S = 12$ V, $V_{CM} = 12$ V, $V_{SENSE} = 100$ mV, $R_L = 10$ k Ω to GND, and $R_{pullup} = 5.1$ k Ω each connected from CMP1 OUT and CMP2 OUT to V_S , unless otherwise noted.

PARAMET	ER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
REFERENCE VOLTAGE						
1.2-V _{REFOUT} Output Voltage			1.188	1.2	1.212	V
Reference Drift	dV _{OUT} /dT	$T_A = -40^{\circ}C$ to $85^{\circ}C$		40	100	ppm/°C
0.6-V _{REF} Output Voltage (Pi pin packages only)	ns 3 and 6 of 14-			0.6		v
Reference Drift	dV _{OUT} /dT	$T_A = -40^{\circ}C$ to $85^{\circ}C$		40	100	ppm/°C
LOAD REGULATION	dV _{OUT} /dI _{LOAD}					
Sourcing		0mA < I _{SOURCE} < 0.5mA		0.4	2	mV/mA
Sinking		$0mA < I_{SINK} < 0.5mA$		0.4		mV/mA
Load Current	I _{LOAD}			1		mA
Line Regulation	dV _{OUT} /dV _S	2.7 V < V _S < 18 V		30		μV/V
CAPACITIVE LOAD						
Reference Output Maximum	Capacitive Load	No Sustained Oscillations		10		nF
OUTPUT IMPEDANCE						
Pins 3 and 6 of 14-Pin Pack	ages Only			10		kΩ

7.8 Electrical Characteristics: General

All specifications at $T_A = 25^{\circ}$ C, $V_S = 12$ V, $V_{CM} = 12$ V, $V_{SENSE} = 100$ mV, $R_L = 10$ k Ω to GND, $R_{pullup} = 5.1$ k Ω each connected from CMP1 OUT and CMP2 OUT to V_S , and CMP1 IN+ = 1 V and CMP2 IN- = GND, unless otherwise noted.

PARAMETER	TEST	CONDITIONS	MIN	ТҮР	MAX	UNIT
POWER SUPPLY						
Operating power supply V _S		$T_A = -40^{\circ}C$ to $125^{\circ}C$	2.7		18	V
Quiescent current I _Q	$V_{OUT} = 2 V$			1.8	2.2	mA
Over temperature	V _{SENSE} = 0 mV				2.8	mA
Comparator power-on reset threshold ⁽¹⁾				1.5		V
TEMPERATURE						
Specified temperature			-40		125	°C
Operating temperature			-55		150	°C

(1) The INA203, INA204, and INA205 are designed to power-up with the comparator in a defined reset state as long as CMP1 RESET is open or grounded. The comparator will be in reset as long as the power supply is below the voltage shown here. The comparator assumes a state based on the comparator input above this supply voltage. If CMP1 RESET is high at power-up, the comparator output comes up high and requires a reset to assume a low state, if appropriate.

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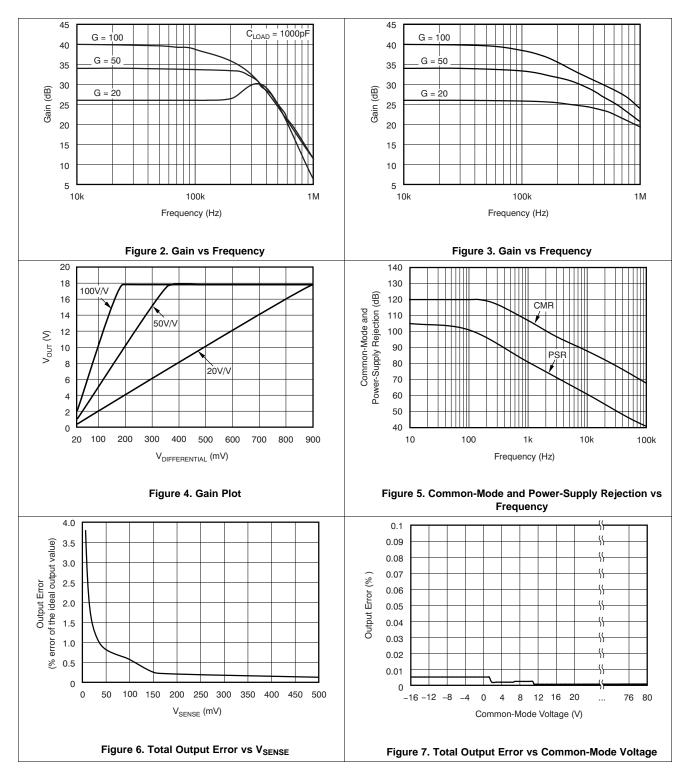


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7.9 Typical Characteristics

All specifications at $T_A = 25^{\circ}C$, $V_S = 12$ V, $V_{CM} = 12$ V, and $V_{SENSE} = 100$ mV, unless otherwise noted.



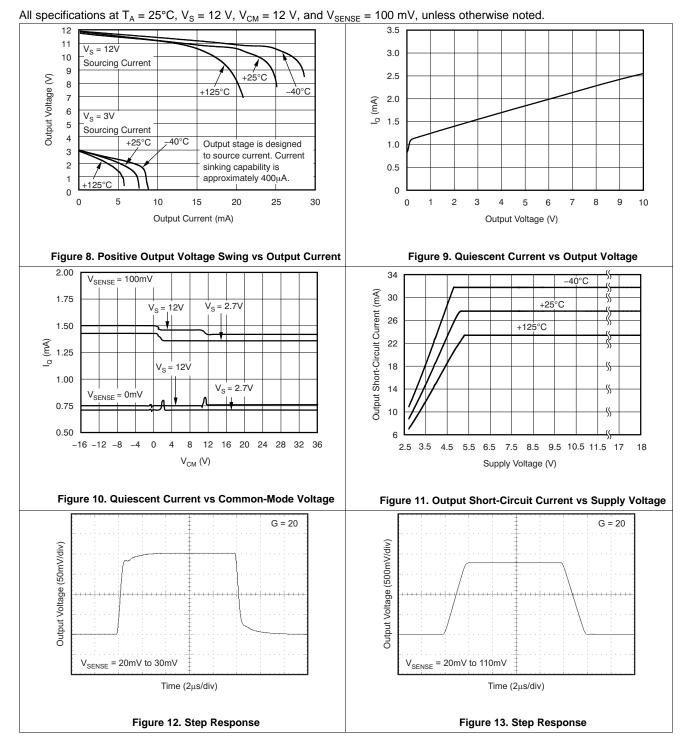


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Typical Characteristics (continued)



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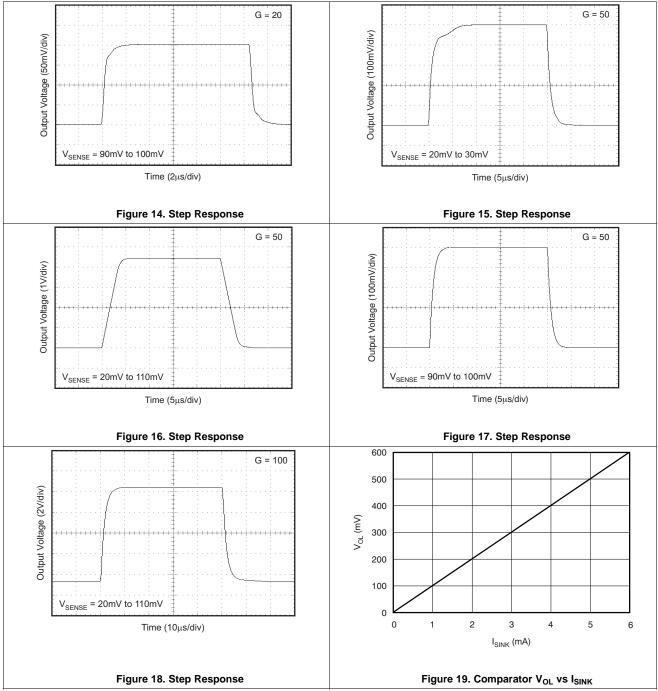
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Typical Characteristics (continued)

All specifications at $T_A = 25^{\circ}$ C, $V_S = 12$ V, $V_{CM} = 12$ V, and $V_{SENSE} = 100$ mV, unless otherwise noted.



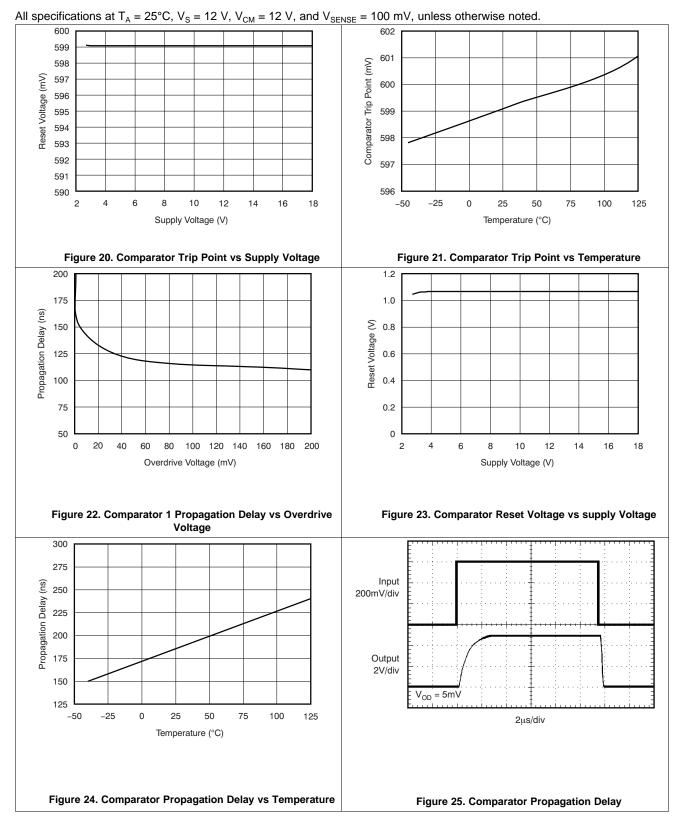


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Typical Characteristics (continued)



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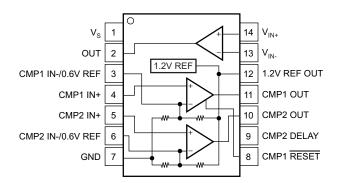
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8 Detailed Description

8.1 Overview

The INA203, INA204, and INA205 are a family of unidirectional current-shunt monitors with voltage output, dual comparators, and voltage reference. The INA203, INA204, and INA205 can sense drops across shunts at common-mode voltages from -16 V to 80 V. The INA203, INA204, and INA205 are available with three output voltage scales: 20 V/V, 50 V/V, and 100 V/V, with up to 500-kHz bandwidth. The INA203, INA204, and INA205 also incorporate two open-drain comparators with internal 0.6-V references. On 14-pin versions, the comparator references can be overridden by external inputs. Comparator 1 includes a latching capability, and Comparator 2 has a user-programmable delay. 14-pin versions also provide a 1.2-V reference output. The INA203, INA204, and INA205 operate from a single 2.7-V to 18-V supply. They are specified over the extended operating temperature range of -40° C to 125°C.

8.2 Functional Block Diagrams





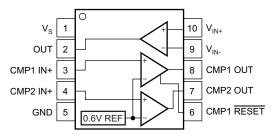


Figure 27. VSSOP-10 Functional Block Diagram

8.3 Feature Description

8.3.1 Basic Connections

Figure 28 shows the basic connections of the INA203, INA204, and INA205. The input pins, V_{IN+} and V_{IN-} , should be connected as closely as possible to the shunt resistor to minimize any resistance in series with the shunt resistance.

Power-supply bypass capacitors are required for stability. Applications with noisy or high-impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.



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INA203, INA204, INA205

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Feature Description (continued)

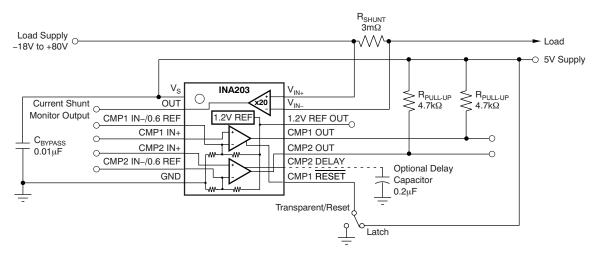


Figure 28. INA20x Basic Connection

8.3.2 Selecting R_{SHUNT}

The value chosen for the shunt resistor, R_{SHUNT} , depends on the application and is a compromise between smallsignal accuracy and maximum permissible voltage loss in the measurement line. High values of R_{SHUNT} provide better accuracy at lower currents by minimizing the effects of offset, while low values of R_{SHUNT} minimize voltage loss in the supply line. For most applications, best performance is attained with an R_{SHUNT} value that provides a full-scale shunt voltage range of 50 mV to 100 mV. Maximum input voltage for accurate measurements is ($V_{SHUNT} - 0.25$) / Gain.

8.3.3 Comparator

The INA203, INA204, and INA205 devices incorporate two open-drain comparators. These comparators typically have 2 mV of offset and a 1.3-µs (typical) response time. The output of Comparator 1 latches and is reset through the CMP1 RESET pin, as shown in Figure 30. This configuration applies to both the 10- and 14-pin versions. Figure 29 illustrates the comparator delay.

The 14-pin versions of the INA203, INA204, and INA205 devices include additional features for comparator functions. The comparator reference voltage of both Comparator 1 and Comparator 2 can be overridden by external inputs for increased design flexibility. Comparator 2 has a programmable delay.

8.3.4 Comparator Delay (14-Pin Version Only)

The Comparator 2 programmable delay is controlled by a capacitor connected to the CMP2 Delay Pin; see Figure 28. The capacitor value (in μ F) is selected by using Equation 1:

$$C_{DELAY}$$
 (in μF) = $\frac{t_D}{5}$

(1)

A simplified version of the delay circuit for Comparator 2 is shown in Figure 29. The delay comparator consists of two comparator stages with the delay between them. I1 and I2 cannot be turned on simultaneously; I1 corresponds to a U1 low output and I2 corresponds to a U1 high output. Using an initial assumption that the U1 output is low, I1 is on, then U2 +IN is zero. If U1 goes high, I2 supplies 120 nA to C_{DELAY} . The voltage at U2 +IN begins to ramp toward a 0.6-V threshold. When the voltage crosses this threshold, the U2 output goes high while the voltage at U2 +IN continues to ramp up to a maximum of 1.2 V when given sufficient time (twice the value of the delay specified for C_{DELAY}). This entire sequence is reversed when the comparator outputs go low, so that returning to low exhibits the same delay.

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Feature Description (continued)

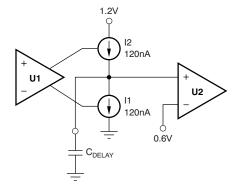


Figure 29. Simplified Model of the Comparator 2 Delay Circuit

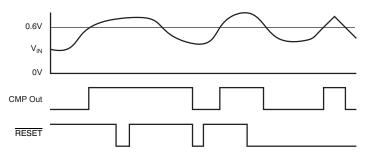


Figure 30. Comparator Latching Capability

Take care to note what will happen if events occur more rapidly than the delay timeout; for example, when the U1 output goes high (turning on I2), but returns low (turning I1 back on) prior to reaching the 0.6-V transition for U2. The voltage at U2 +IN ramps back down at a rate determined by the value of C_{DELAY} , and only returns to zero if given sufficient time.

In essence, when analyzing Comparator 2 for behavior with events more rapid than its delay setting, use the model shown in Figure 29.

8.3.5 Comparator Maximum Input Voltage Range

The maximum voltage at the comparator input for normal operation is up to (Vs) - 1.5 V. There are special considerations when overdriving the reference inputs (pins 3 and 6). Driving either or both inputs high enough to drive 1 mA back into the reference introduces errors into the reference. Figure 31 shows the basic input structure. A general guideline is to limit the voltage on both inputs to a total of 20 V. The exact limit depends on the available voltage and whether either or both inputs are subject to the large voltage. When making this determination, consider the 20 k Ω from each input back to the comparator. Figure 32 shows the maximum input voltage that avoids creating a reference error when driving both inputs (an equivalent resistance back into the reference of 10 k Ω).

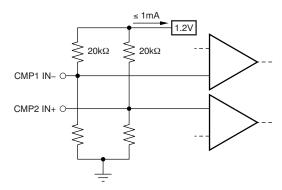


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Feature Description (continued)





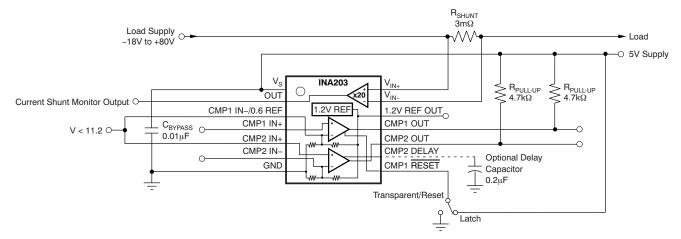


Figure 32. Overdriving Comparator Inputs Without Generating a Reference Error

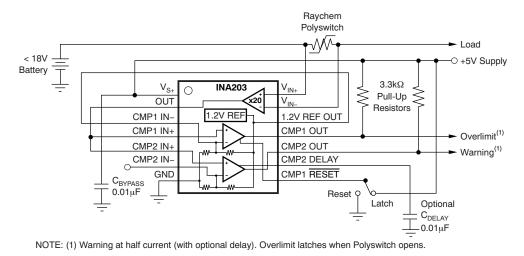


Figure 33. Polyswitch Warning and Fault Detection Circuit



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Feature Description (continued)

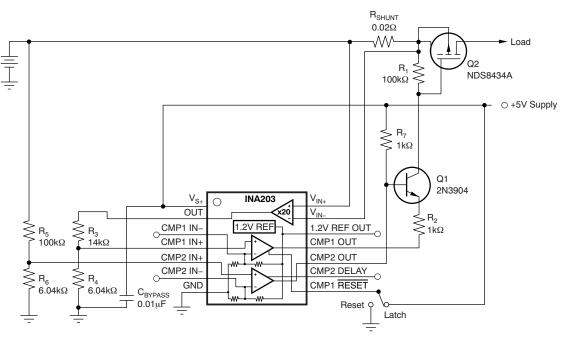


Figure 34. Lead-Acid Battery Protection Circuit

8.4 Device Functional Modes

8.4.1 Input Filtering

An obvious and straightforward location for filtering is at the output of the INA203, INA204, and INA205 series; however, this location negates the advantage of the low output impedance of the internal buffer. The only other option for filtering is at the input pins of the INA203, INA204, and INA205, which is complicated by the internal 5 k Ω + 30% input impedance; this configuration is illustrated in Figure 35. Using the lowest possible resistor values minimizes both the initial shift in gain and effects of tolerance. Use Equation 2 to calculate the effect on initial gain.

Gain Error % = 100 -
$$\left[100 \times \frac{5k\Omega}{5k\Omega + R_{FILT}}\right]$$
 (2)

Total effect on gain error can be calculated by replacing the 5-k Ω term with 5 k Ω – 30%, (or 3.5 k Ω) or 5 k Ω + 30% (or 6.5 k Ω). The tolerance extremes of R_{FILT} can also be inserted into the equation. If a pair of 100 Ω 1% resistors are used on the inputs, the initial gain error will be 1.96%. Worst-case tolerance conditions will always occur at the lower excursion of the internal 5-k Ω resistor (3.5 k Ω), and the higher excursion of R_{FILT} – 3% in this case.



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Device Functional Modes (continued)

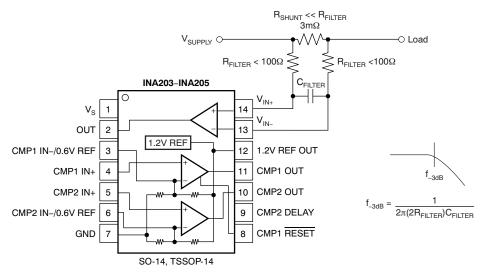


Figure 35. Input Filter (Gain Error: 1.5% to –2.2%)

The specified accuracy of the INA203, INA204, and INA205 must then be combined in addition to these tolerances. While this discussion treated accuracy worst-case conditions by combining the extremes of the resistor values, it is appropriate to use geometric mean or root sum square calculations to total the effects of accuracy variations.

8.4.2 Accuracy Variations as a Result Of V_{SENSE} and Common-Mode Voltage

The accuracy of the INA203, INA204, and INA205 current shunt monitors is a function of two main variables: $V_{SENSE} (V_{IN+} - V_{IN-})$ and common-mode voltage, V_{CM} , relative to the supply voltage, V_S . V_{CM} is expressed as $(V_{IN+} + V_{IN-}) / 2$; however, in practice, V_{CM} is seen as the voltage at V_{IN+} because the voltage drop across V_{SENSE} is usually small.

This section addresses the accuracy of these specific operating regions:

- Normal Case 1: $V_{SENSE} \ge 20 \text{ mV}, V_{CM} \ge V_S$
- Normal Case 2: V_{SENSE} ≥ 20 mV, V_{CM} < V_S
- Low V_{SENSE} Case 1: $V_{SENSE} < 20 \text{ mV}$, -16 V $\leq V_{CM} < 0$
- Low V_{SENSE} Case 2: V_{SENSE} < 20 mV, 0 V ≤ V_{CM} ≤ V_S
- Low V_{SENSE} Case 3: $V_{SENSE} < 20 \text{ mV}$, $V_S < V_{CM} \le 80 \text{ V}$

8.4.2.1 Normal Case 1: $V_{SENSE} \ge 20 \text{ mV}, V_{CM} \ge V_{S}$

This region of operation provides the highest accuracy. Here, the input offset voltage is characterized and measured using a two-step method. First, the gain is determined by Equation 3.

$$G = \frac{V_{OUT1} - V_{OUT2}}{100mV - 20mV}$$

where

- V_{OUT1} = Output Voltage with V_{SENSE} = 100 mV.
- V_{OUT2} = Output Voltage with V_{SENSE} = 20 mV.

Then the offset voltage is measured at V_{SENSE} = 100 mV and referred to the input (RTI) of the current shunt monitor, as shown in Equation 4.

$$V_{OS}RTI$$
 (Referred-To-Input) = $\left(\frac{V_{OUT1}}{G}\right)$ – 100mV

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(4)

(3)



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Device Functional Modes (continued)

In the *Typical Characteristics*, Figure 7 shows the highest accuracy for this region of operation. In this plot, $V_S = 12 \text{ V}$; for $V_{CM} \ge 12 \text{ V}$, the output error is at its minimum. This case is also used to create the $V_{SENSE} \ge 20\text{-mV}$ output specifications in the *Electrical Characteristics: Current-Shunt Monitor* table.

8.4.2.2 Normal Case 2: $V_{SENSE} \ge 20 \text{ mV}$, $V_{CM} < V_S$

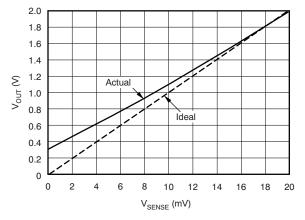
This region of operation has slightly less accuracy than Normal Case 1 as a result of the common-mode operating area in which the part functions, as seen in Figure 7. As noted, for this graph $V_S = 12$ V; for $V_{CM} < 12$ V, the Output Error increases as V_{CM} becomes less than 12 V, with a typical maximum error of 0.005% at the most negative $V_{CM} = -16$ V.

8.4.2.3 Low V_{SENSE} Case 1

- $V_{SENSE} < 20 \text{ mV}, -16 \text{ V} \le V_{CM} < 0;$
- Low V _{SENSE} Case 3:
- $V_{SENSE} < 20 \text{ mV}, V_S < V_{CM} \le 80 \text{ V}$

Although the INA203 family of devices are not designed for accurate operation in either of these regions, some applications are exposed to these conditions; for example, when monitoring power supplies that are switched on and off while V_S is still applied to the INA203, INA204, or INA205. Take care to know what the behavior of the devices will be in these regions.

As V_{SENSE} approaches 0 mV, in these V_{CM} regions, the device output accuracy degrades. A larger-than-normal offset can appear at the current shunt monitor output with a typical maximum value of V_{OUT} = 300 mV for V_{SENSE} = 0 mV. As V_{SENSE} approaches 20 mV, V_{OUT} returns to the expected output value with accuracy as specified in the *Electrical Characteristics: Current-Shunt Monitor*. Figure 36 illustrates this effect using the INA205 (Gain = 100).





8.4.2.4 Low V_{SENSE} Case 2: $V_{SENSE} < 20 \text{ mV}$, $0 \text{ V} \le V_{CM} \le V_S$

This region of operation is the least accurate for the INA203 family. To achieve the wide input common-mode voltage range, these devices use two op amp front ends in parallel. One operational amplifier front end operates in the positive input common-mode voltage range, and the other in the negative input region. For this case, neither of these two internal amplifiers dominates and overall loop gain is very low. Within this region, V_{OUT} approaches voltages close to linear operation levels for Normal Case 2. This deviation from linear operation becomes greatest the closer V_{SENSE} approaches 0 V. Within this region, as V_{SENSE} approaches 20 mV, device operation is closer to that described by Normal Case 2. Figure 37 illustrates this behavior for the INA205. The V_{OUT} maximum peak for this case is tested by maintaining a constant V_S , setting $V_{SENSE} = 0$ mV, and sweeping V_{CM} from 0 V to V_S . The exact V_{CM} at which V_{OUT} peaks during this test varies from part to part, but the V_{OUT} maximum peak is tested to be less than the specified V_{OUT} Tested Limit.

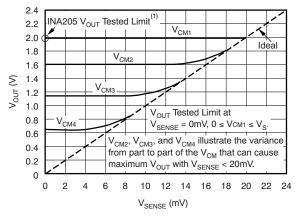


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Device Functional Modes (continued)



NOTE: (1) INA203 V_{OUT} Tested Limit = 0.4V. INA204 V_{OUT} Tested Limit = 1V.

8.4.3 Transient Protection

The –16 V to 80 V common-mode range of the INA203, INA204, and INA205 is ideal for withstanding automotive fault conditions ranging from 12-V battery reversal up to 80-V transients, since no additional protective components are needed up to those levels. In the event that the INA203, INA204, and INA205 are exposed to transients on the inputs in excess of their ratings, then external transient absorption with semiconductor transient absorbers (Zeners or *Transzorbs*) are necessary. Use of metal oxide varistors (MOVs) or video disk recorders (VDRs) is not recommended except when they are used in addition to a semiconductor transient absorber. Select the transient absorber such that it will never allow the INA203, INA204, and INA205 to be exposed to transients greater than 80 V (that is, allow for transient absorber tolerance, as well as additional voltage because of transient absorber dynamic impedance). Despite the use of internal Zener-type ESD protection, the INA203, INA204, and INA205 do not lend themselves to using external resistors in series with the inputs because the internal gain resistors can vary up to ±30% but are closely matched. (If gain accuracy is not important, then resistors can be added in series with the INA203, INA204, and INA205 inputs with two equal resistors on each input.)

8.4.4 Output Voltage Range

The output of the INA203, INA204, and INA205 is accurate within the output voltage swing range set by the power-supply pin, Vs. This performance is best illustrated when using the INA205 (a gain of 100 version), where a 100-mV full-scale input from the shunt resistor requires an output voltage swing of 10 V, and a power-supply voltage sufficient to achieve 10 V on the output.

8.4.5 Reference

The INA203, INA204, and INA205 include an internal voltage reference that has a load regulation of 0.4 mV/mA (typical), and not more than 100 ppm/°C of drift. Only the 14-pin package allows external access to reference voltages, where voltages of 1.2 V and 0.6 V are both available. Output current versus output voltage is illustrated in the *Typical Characteristics* section.

Figure 37. Example For Low V_{SENSE} Case 2 (INA205, Gain = 100)



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9 Application and Implementation

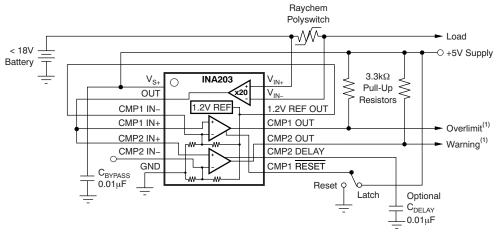
NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The INA203, INA204, and INA205 series is designed to enable easy configuration for detecting overcurrent conditions and current monitoring in an application. This device is also incorporate two open-drain comparators with internal 0.6-V references. On 14-pin versions, the comparator references can be overridden by external inputs. Comparator 1 includes a latching capability, and Comparator 2 has a user-programmable delay. 14-pin versions also provide a 1.2-V reference output. This device can also be paired with minimum additional devices to create more sophisticated monitoring functional blocks.

9.2 Typical Application



NOTE: (1) Warning at half current (with optional delay). Overlimit latches when Polyswitch opens.

Figure 38. Polyswitch Warning and Fault Detection Circuit

9.2.1 Design Requirements

The device measures current through a resistive shunt with current flowing in one direction, thus enabling detection of an overlimit or warning event only when the differential input voltage exceeds the corresponding threshold limits. When the current reaches the warning limit of 0.6 V, the output of CMP2 will transition high indicating a warning condition. When the current futher increases to or past the overlimit limit of 1.2 V, the output of CMP1 will transition high indicating an overlimit condition. Optional C_{DELAY} can be sized to add delay to CMP1.

9.2.2 Detailed Design Procedure

Figure 38 shows the basic connections of the device. The input terminals, IN+ and IN–, should be connected as closely as possible to the current-sensing resistor or polymeric switch to minimize any resistance in series with the shunt resistance. Additional resistance between the current-sensing resistor and input terminals can result in errors in the measurement. When input current flows through this external input resistance, the voltage developed across the shunt resistor can differ from the voltage reaching the input terminals.



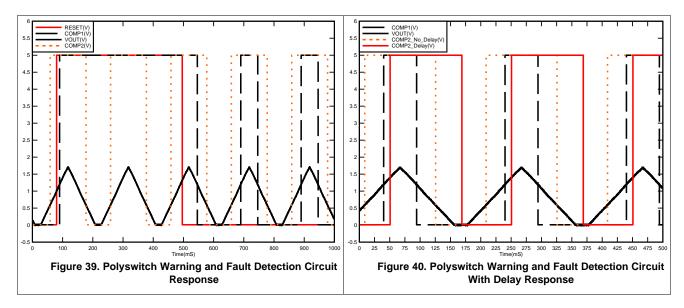
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Typical Application (continued)

9.2.3 Application Curves





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10 Power Supply Recommendations

The input circuitry of the INA203, INA204, and INA205 can accurately measure beyond the power-supply voltage, Vs. For example, the Vs power supply can be 5 V, whereas the load power-supply voltage is up to 80 V. The output voltage range of the OUT terminal, however, is limited by the voltages on the power-supply pin.

11 Layout

11.1 Layout Guidelines

- Connect the input pins to the sensing resistor using a Kelvin or 4-wire connection. This connection technique
 ensures that only the current-sensing resistor impedance is detected between the input pins. Poor routing of
 the current-sensing resistor commonly results in additional resistance present between the input pins. Given
 the very low ohmic value of the current resistor, any additional high-current carrying impedance can cause
 significant measurement errors.
- The power-supply bypass capacitor should be placed as closely as possible to the supply and ground pins. The recommended value of this bypass capacitor is 0.1 µF. Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.

11.2 Layout Example

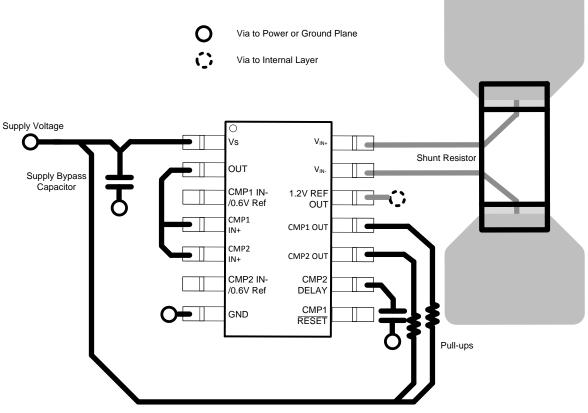


Figure 41. Layout Recommendation



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12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
INA203	Click here	Click here	Click here	Click here	Click here
INA204	Click here	Click here	Click here	Click here	Click here
INA205	Click here	Click here	Click here	Click here	Click here

Table 3. Related Links

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



7-Apr-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
INA203AID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA203A	Samples
INA203AIDGSR	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	BQN	Samples
INA203AIDGST	ACTIVE	VSSOP	DGS	10	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	BQN	Samples
INA203AIDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA203A	Samples
INA203AIPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA203A	Samples
INA203AIPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA203A	Samples
INA204AID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA204A	Samples
INA204AIDGSR	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	BQO	Samples
INA204AIDGST	ACTIVE	VSSOP	DGS	10	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	BQO	Samples
INA204AIDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA204A	Samples
INA204AIPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA204A	Samples
INA204AIPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA204A	Samples
INA205AID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA205A	Samples
INA205AIDGSR	ACTIVE	VSSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	BQP	Sample
INA205AIDGST	ACTIVE	VSSOP	DGS	10	250	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	BQP	Sample
INA205AIDR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA205A	Sample
INA205AIPW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA205A	Sample

Addendum-Page 1



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Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
INA205AIPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	INA205A	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

ILFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect. NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/(Fee conversion plan has not been defined. Pb-Free (ReHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width

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OTHER QUALIFIED VERSIONS OF INA203 :

Addendum-Page 2



7-Apr-2016

NOTE: Qualified Version Definitions:

Automotive: INA203-Q1

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

Addendum-Page 3



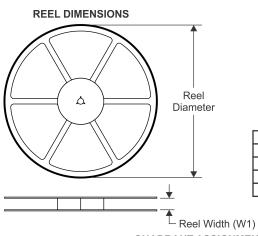
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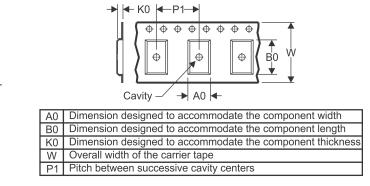
TEXAS INSTRUMENTS

PACKAGE MATERIALS INFORMATION

25-Nov-2015

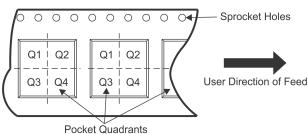
TAPE AND REEL INFORMATION





TAPE DIMENSIONS

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA203AIDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA203AIDGST	VSSOP	DGS	10	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA203AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
INA203AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
INA204AIDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA204AIDGST	VSSOP	DGS	10	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA204AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
INA204AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
INA205AIDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA205AIDGST	VSSOP	DGS	10	250	180.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
INA205AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
INA205AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

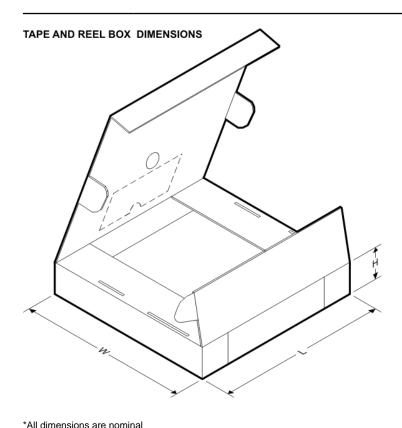


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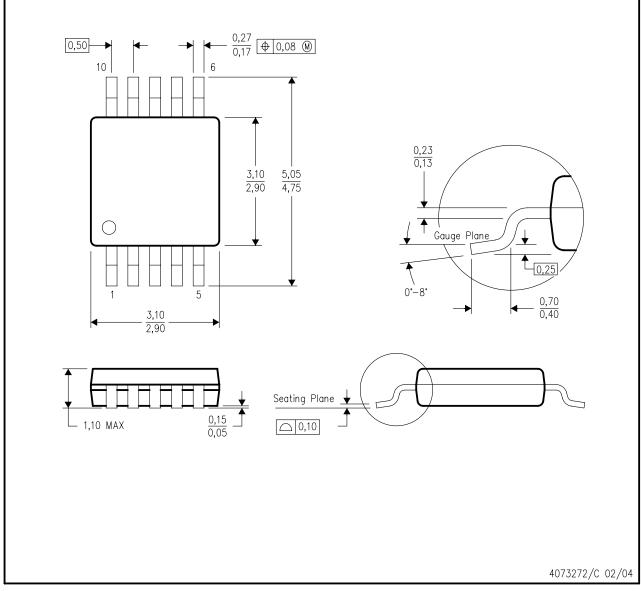
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA203AIDGSR	VSSOP	DGS	10	2500	367.0	367.0	35.0
INA203AIDGST	VSSOP	DGS	10	250	210.0	185.0	35.0
INA203AIDR	SOIC	D	14	2500	367.0	367.0	38.0
INA203AIPWR	TSSOP	PW	14	2000	367.0	367.0	35.0
INA204AIDGSR	VSSOP	DGS	10	2500	367.0	367.0	35.0
INA204AIDGST	VSSOP	DGS	10	250	210.0	185.0	35.0
INA204AIDR	SOIC	D	14	2500	367.0	367.0	38.0
INA204AIPWR	TSSOP	PW	14	2000	367.0	367.0	35.0
INA205AIDGSR	VSSOP	DGS	10	2500	367.0	367.0	35.0
INA205AIDGST	VSSOP	DGS	10	250	210.0	185.0	35.0
INA205AIDR	SOIC	D	14	2500	367.0	367.0	38.0
INA205AIPWR	TSSOP	PW	14	2000	367.0	367.0	35.0



MECHANICAL DATA

DGS (S-PDSO-G10)

PLASTIC SMALL-OUTLINE PACKAGE



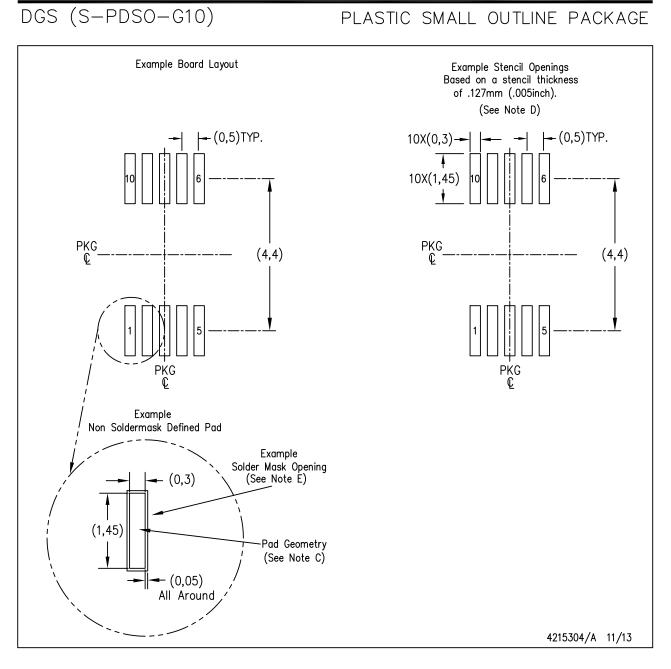
NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation BA.





LAND PATTERN DATA



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
- contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations. E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

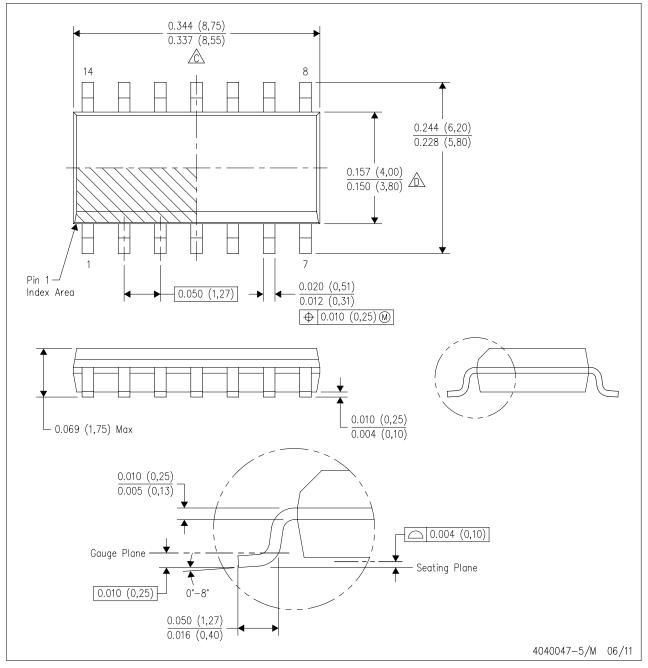




MECHANICAL DATA

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

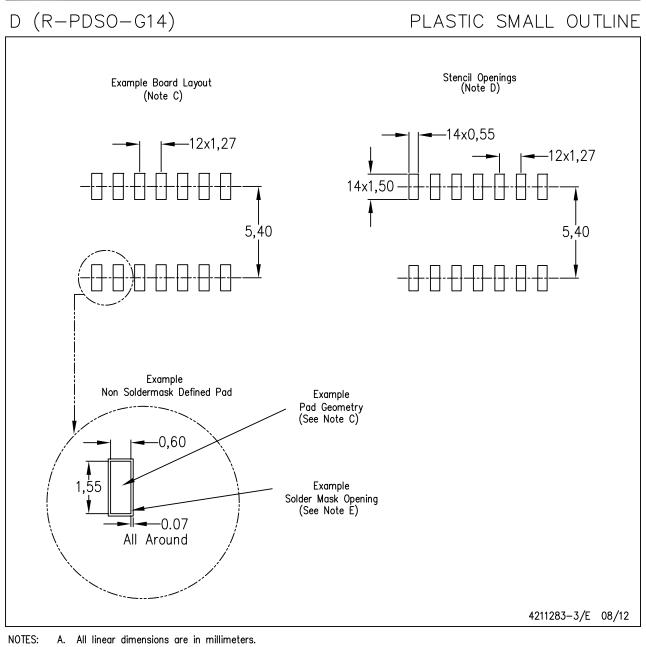
A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





LAND PATTERN DATA



- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

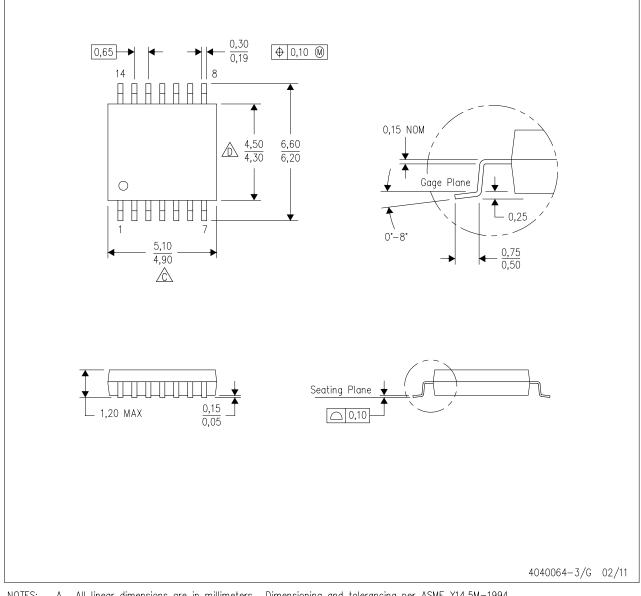




MECHANICAL DATA

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α. Ŗ. This drawing is subject to change without notice. \triangle Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall

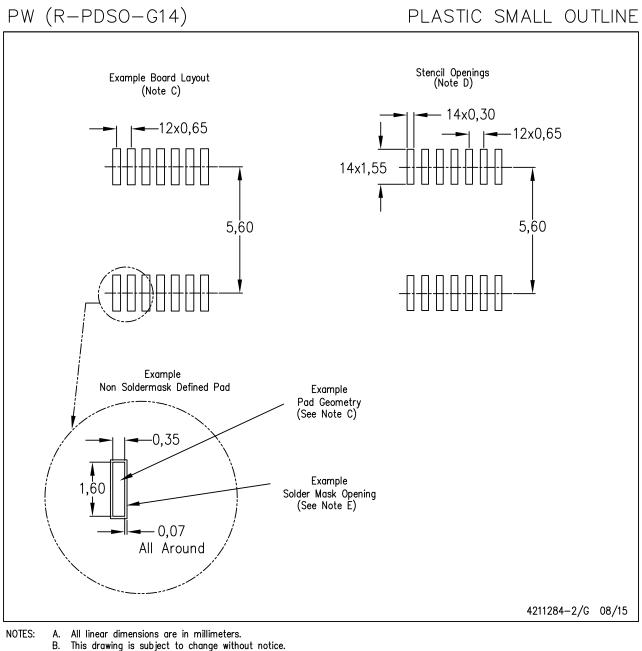
not exceed 0,15 each side. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





LAND PATTERN DATA



- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





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